NSN 5961-01-331-4105

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-331-4105

Inclosure Material:	
Plastic	
Overall Length:	
Between 14.23 millimeters and 15.87 millimete	rs
Terminal Length:	
Between 2.04 millimeters and 2.92 millimeters	
Overall Height:	
Between 3.56 millimeters and 4.82 millimeters	
Overall Width:	
Between 9.66 millimeters and 10.66 millimeters	3
Mounting Facility Quantity:	
1	
Internal Configuration:	
Junction contact	
Joint Electronic Device Engineering Counci	I/jedec/case Outline Designation:
To-220	
Mounting Method:	
Terminal and unthreaded hole	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
80.0 breakdown voltage, collector-to-base, er	mitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown
voltage, emitter-to-base, collector open	
Current Rating Per Characteristic:	
10.00 amperes source cutoff current	
Power Rating Per Characteristic:	
50.0 watts small-signal input power, common-	collector absolute
Transfer Ratio:	
60.0 static forward current transfer ratio, comr	non-emitter
Special Features:	
Junction pattern arrangement: pnp	
Terminal Type And Quantity:	
3 pin	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	